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AN1101SSM

CMOS single power supply

Overview

AN1101SSM is an operational amplifier with a single power supply by CMOS diffusion process.

It has low current-consumption compared to general purpose operational amplifier by bipolar diffusion process. 0 V to V_{DD} is available for both input voltage and output voltage. And this IC is widely applicable to the buttery-driven equipment and to many amplifier circuits which adopt small package products.

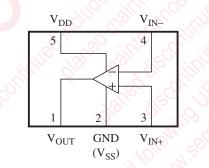
Features

- Low current-consumption: $I_{DD} = 55 \,\mu A$ (typ.), $V_{DD} = 3 \,V$
- Operating input/output voltage range: 0 V to V_{DD}
- Small offset voltage: 0.5 mV (typ.)
- Small input bias current: 1 pA (typ.)
- Operating supply voltage range:
 - 2.5 V to 5.5 V or ± 1.25 V to ± 2.75 V

Applications

• Various small-size general consumer electronics equipment

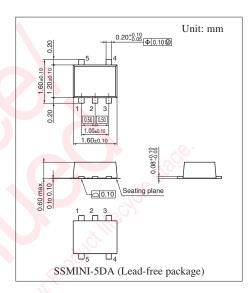
Block Diagram



Pin Descriptions

Pin No.	Symbol	Description
1	V _{OUT}	Output
2	GND (V _{SS})	Ground, V_{SS} (negative supply) at using two power supply
3	V _{IN+}	Input (positive)
4	V _{IN-}	Input (negative)
5	V _{DD}	Power supply

Note) The AN1101SSM has been designed for general consumer electronics equipment, not for the specific one requiring such a high reliability that may prevent it from threatening the human lives.



Absolute Maximum Ratings

Parameter	Symbol	Rating	Unit	
Supply voltage	V _{DD}	5.6	V	
Differential input voltage	DV _{IN}	±5.6	V	
Input voltage	V _{IN}	V _{SS} to V _{DD}	V	
Supply current	I _{DD}	_	mA	
Power dissipation *2	P _D	50	mW	
Operating ambient temperature *1	T _{opr}	-30 to +85	°C	
Storage temperature *1	T _{stg}	-55 to +125	°C	

Note) 1. *1: Except for the operating ambient temperature and storage temperature, all ratings are for $T_a = 25^{\circ}C$.

*2: The value at $T_a = +85^{\circ}C$.

2. This IC is not suitable for car electrical equipment.

Recommended Operating Range

Parameter	Symbol	Range	Unit
Supply voltage	V _{DD}	2.5 to 5.5	V
		±1.25 to ±2.75	

Electrical Characteristics at $V_{DD} = 3.0 V$, $V_{SS} = GND$, $T_a = 25^{\circ}C \pm 2^{\circ}C$						
Parameter	Symbol	Conditions	Min	Тур	Max	Unit
Input offset voltage	V _{IO}	Buffer circuit	<u>8</u>	0.5	5.5	mV
Common-mode input voltage	CMV _{IN}	$R_{\rm S} = 10 \text{ k}\Omega, R_{\rm F} = 10 \text{ k}\Omega$	0	1	- 3	V
Open-loop gain	GV	f = 100 Hz	60	90	\mathcal{O}	dB
Maximum output amplitude voltage 1	V _{OH}	$R_L \ge 10 \text{ k}\Omega$	2.90	2.98	—	V
Maximum output amplitude voltage 2	VOL	$R_L \ge 10 \text{ k}\Omega$	2-2	0.01	0.05	V
Common-mode input voltage rejection ratio	CMRR	$V_{IN} = 0.0 \text{ V to } 3.0 \text{ V}, R_S = R_F = 10 \text{ k}\Omega$	50	65		dB
Supply voltage ripple rejection ratio *	SVRR	$V_{DD} = 2.5 \text{ V to } 5.5 \text{ V}$	55	70	_	dB
Supply current	I _{DD}	No load		55	100	μΑ

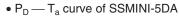
Note) * : Except for the supply voltage ripple rejection ratio (SVRR), $V_{DD} = 3 V$.

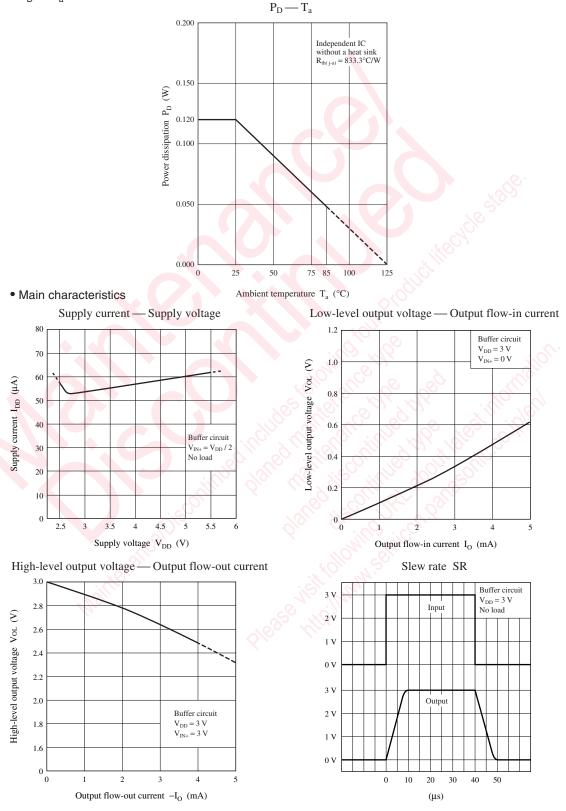
• Design reference data

Note) The characteristics listed below are theoretical values based on the IC design and are not guaranteed.

Parameter	Symbol	Conditions	Reference	Unit
Offset current	I _O	—	1	pА
Input bias current	I _{IO}	_	1	pА
Slew rate	SR	$R_L \ge 10 \text{ k}\Omega$	0.35	V/µs
Zero-cross frequency	f _T	$A_V = 1$	0.8	MHz

Technical Data

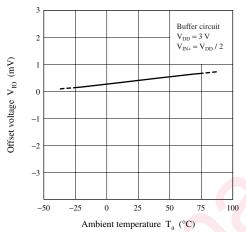




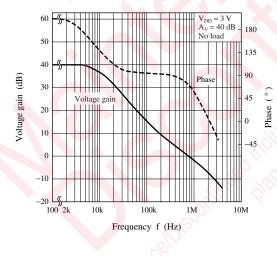
Technical Data (continued)

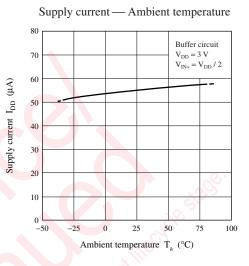
Main characteristics (continued)

Offset voltage - Ambient temperature

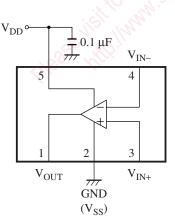


Voltage gain · Phase — Frequency characteristics





Application Circuit Example



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